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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

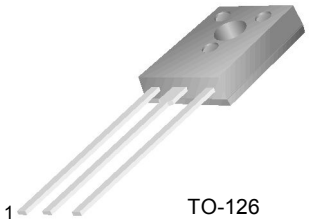
FAIRCHILD SEMICONDUCTOR®

March 2008

KSE13003
NPN Silicon Transistor

High Voltage Switch Mode Applications

- High Voltage Capability
- High Speed Switching
- Suitable for Switching Regulator and Motor Control



TO-126

1. Emitter 2.Collector 3.Base

Absolute Maximum Ratings* T_C = 25°C unless otherwise noted **(notes_1)**

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	1.5	A
I_{CP}	Collector Current (Pulse)	3	A
I_B	Base Current	0.75	A
P_C	Collector Dissipation (T_C = 25°C)	20	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-65 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
NOTES_1:
1) These ratings are based on a maximum junction temperature of 150°C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

h_{FE} Classification

Classification	H1	H2	H3
h_{FE}*	9 ~ 16	14~ 21	19 ~ 26

* Test on V_{CE} = 2V, I_C = 0.5A.

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 5mA, I_B = 0	400			V
I_{EBO}	Emitter Cut-off Current	V_{EB} = 9V, I_C = 0			10	μA
h_{FE}	*DC Current Gain	V_{CE} = 2V, I_C = 0.5A V_{CE} = 2V, I_C =1A	8 5		40	
V_{CE}(sat)	*Collector Emitter Saturation Voltage	I_C = 0.5A, I_B = 0.1A I_C = 1A, I_B = 0.25A I_C = 1.5A, I_B = 0.5A			0.5 1 3	V V V
V_{BE}(sat)	*Base Emitter Saturation Voltage	I_C = 0.5A, I_B = 0.1A I_C = 1A, I_B = 0.25A			1 1.2	V V
C_{ob}	Output Capacitance	V_{CB} = 10V , f = 0.1MHz		21		pF
f_T	Current Gain Bandwidth Product	V_{CE} = 10V, I_C = 0.1A	4			MHz
t_{ON}	Turn On Time	V_{CC} =125V, I_C = 1A I_{B1} = 0.2A, I_{B2} = - 0.2A R_L = 125W			1.1	ms
t_{STG}	Storage Time				4.0	ms
t_F	Fall Time				0.7	ms

* Pulse Test: Pulse Width=5ms, Duty Cycle≤10%

Package Marking and Ordering Information

Device Item (notes_2)	Device Marking	Package	Packing Method	Remarks
KSE13003H1ASTU	1 E13003	TO-126	TUBE	
KSE13003H2ASTU	2 E13003	TO-126	TUBE	
KSE13003H3ASTU	3 E13003	TO-126	TUBE	

Notes_2 :

1) The Affix "-H1/-H2/-H3" means the hFE classification.

2) The Sufix "-STU" means the TO126 short lead package and the Tube packing method, which can be on fairchildsemi website at http://www.fairchildsemi.com

Typical Performance Characteristics

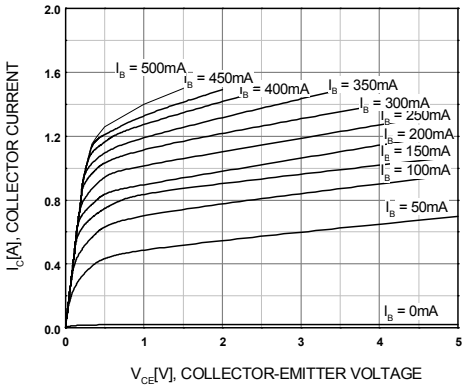


Figure 1. Static Characteristic

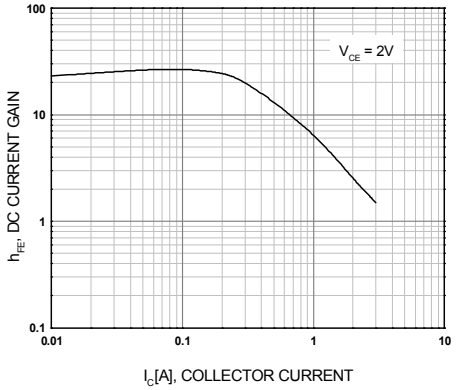


Figure 2. DC current Gain

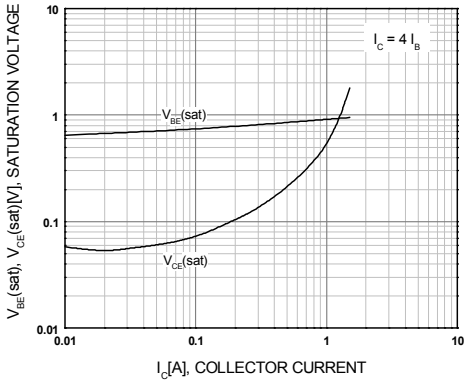


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

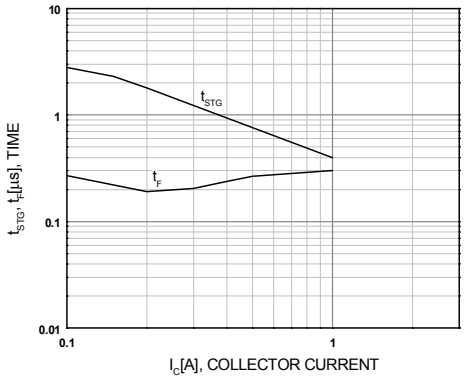


Figure 4. Switching Time

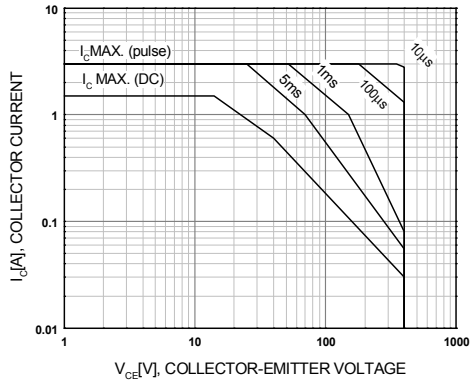


Figure 5. Safe Operating Area

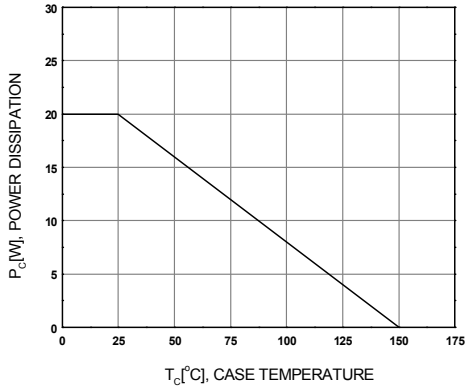


Figure 6. Power Derating

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Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	This datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I34

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